

程序升温表面反应技术研究氧化铈上 H₂S 的吸附和转化刘冰^{1,2}, 徐恒泳^{2,a}, 张泽会^{1,b}¹中南民族大学催化材料教育部-国家民委共建重点实验室, 湖北武汉 430074²中国科学院大连化学物理研究所, 辽宁大连 116023

摘要: 采用程序升温表面反应技术研究了 H₂S 在 CeO₂, TiO₂ 和 Al₂O₃ 三种载体上的吸附和反应行为。结果表明, CeO₂ 具有最强的脱硫能力。系统研究了预处理气氛对 H₂S 在 CeO₂ 上吸附和反应行为。发现 CeO₂ 的脱硫能力在惰性气氛、还原性气氛、氧化性气氛中依次增强。H₂S 首先吸附在经预处理的 CeO₂ 表面, 进一步在 Ar 氛围下升温脱附时, 一部分 H₂S 在 673 K 以下脱附, 部分则与 CeO₂ 表面氧反应, 在 473 K 下产生硫和水, 而在 473~673 K 温度范围内, 生成 SO₂。在 673 K 以上, 所生成的 SO₂ 进一步与晶格氧反应, 转化成硫酸盐。后者在 873 K 再次分解为 SO₂。因此, CeO₂ 表面脱硫过程应控制在 673 K 以下, 可避免复杂的再生过程。

关键词: 氧化铈; 硫化氢; 吸附; 程序升温表面反应

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Temperature-Programmed Surface Reaction Study of Adsorption and Reaction of H₂S on CeriaLIU Bing^{1,2}, XU Hengyong^{2,a}, ZHANG Zehui^{1,b}¹Key Laboratory of Catalysis and Materials Sciences of the State Ethnic Affairs Commission & Ministry of Education, College of Chemistry and Material Science, South-Central University for Nationalities, Wuhan 430074, Hubei, China²Dalian Institute of Chemical Physics, Chinese Academy of Sciences, Dalian 116023, Liaoning, China

Abstract: H₂S adsorption and reaction on CeO₂, TiO₂, and γ -Al₂O₃ were studied by temperature programmed surface reaction (TPSR). Ceria had the best desulfidation ability. The pretreatment atmosphere affected H₂S adsorption and reaction on ceria, and desulfidation efficiency increased in the order of inert atmosphere, reducing atmosphere, oxidizing atmosphere. H₂S was first adsorbed on pretreated ceria at room temperature. On increasing the temperature in an Ar (99.99%) atmosphere, part of the H₂S desorbed below 673 K, and another part reacted with the surface oxygen on ceria to produce sulfur and water below 473 K, and SO₂ between 473 and 673 K, which further reacted with lattice oxygen and was transformed into sulfate above 673 K. The sulfate decomposed into SO₂ again at 873 K. To avoid the complex regeneration, it is advisable to carry out desulfidation below 673 K when using ceria as adsorbent.

Key words: ceria; hydrogen sulfide; adsorption; temperature-programmed surface reaction

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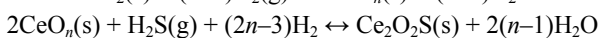
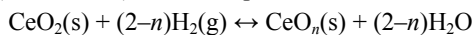
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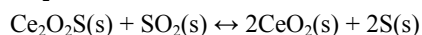
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The production of hydrogen from a heavy oil for a solid oxide fuel cell is a clean and efficient way to generate renewable energy. However, heavy oils usually contain sulfur species. H₂S is often produced during the gasification of heavy oils and would exist in the syngas [1]. For instance, 0.002% H₂S is still present in syngas from the integrated gasification combined cycle (IGCC) process [2]. This H₂S should be removed because it is a corrosive gas and it will deactivate most catalysts [3,4].

Many methods have been developed to remove H₂S, including physical adsorption, chemical adsorption, chemical oxidation, and catalytic combustion [5,6]. Among these methods, physical adsorption and chemical adsorption are the preferred methods. Rare earth oxides, especially ceria, have excellent desulfidation ability and are thermodynamically favorable [7]. Zheng et al. [8] have reported an efficient method for the removal of H₂S by reduced cerium oxide (CeO_{*n*}, *n* < 2). The adsorption reactions were



If the bulk ceria adsorbent gets deeply sulfided, Ce₂O₂S is formed in a reducing atmosphere. Then the adsorption is quickly degraded, and a regeneration step is needed to reproduce CeO₂ as follows:



This complex regeneration step usually causes a structural change of the adsorbent during the transformation from the sulfide to oxide phase [9,10]. However, the structural change of the adsorbent can be avoided by controlling the sulfidation and regeneration processes using a low temperature and high gas velocity [7]. On the other hand, it is important to understand the interaction between H₂S and ceria in different gas atmospheres because ceria is a common support or catalyst for many reactions. Ma et al. [11] studied a sulfur-tolerant CeO₂ supported Pd (Pd/CeO₂) catalyst for methanol synthesis. A bifunctional reaction mechanism on Pd/CeO₂ was proposed. Methanol was formed at the active Pd site. H₂S was first adsorbed on the ceria surface, and then it reacted with surface oxygen to form SO₂. A small amount of oxygen was added into the syngas to fill the oxygen vacancies, which were formed on the surface of ceria. In our previous work, it was shown that Pt/CeO₂ showed good sulfur tolerance in the water gas shift reaction (WGS) in the presence of 0.002% H₂S [12]. However, all of the adsorbed H₂S desorbed in the form of H₂S in the WGS reaction, which was different from the methanol synthesis reaction. It was suggested that H₂S adsorbed competitively with water on oxygen vacancies on the ceria surface in the presence of water vapor, and the SH species produced was desorbed in the form of H₂S by H₂ spillover from platinum.

In this study, the adsorption and reaction of H₂S on CeO₂,

TiO₂, and γ-Al₂O₃ were studied by temperature programmed surface reaction (TPSR) experiments, and the desulfidation conditions were optimized for different gas atmospheres. The study of H₂S adsorption and conversion would be helpful for understanding sulfur-tolerance mechanisms for ceria supported catalysts.

1 Experimental

1.1 Catalyst preparation

Ceria was prepared by co-deposition. An aqueous solution of (NH₄)₂CO₃ and (NH₄)₂Ce(NO₃)₆ was added dropwise to deionized water at 328 K while keeping the pH at 8–9. The slurry mixture was aged at 328 K for 2 h with constant stirring. The precipitate was washed with deionized water several times, then dried at 393 K overnight, and finally calcined at 773 K for 4 h to obtain ceria. TiO₂ was prepared by the hydrolysis of TiO(C₄H₉)₄. TiO(C₄H₉)₄ was first dissolved in ethanol, and then added dropwise to an aqueous solution of (NH₄)₂CO₃. The following steps were the same as those for the preparation of ceria. Commercial γ-Al₂O₃ was purchased from Degussa Co., Ltd (Germany), and was calcined at 773 K for 4 h before use.

1.2 Catalyst characterization

A Quantachrome NOVA-4000 automated adsorption instrument was used to measure N₂ adsorption isotherms at liquid N₂ temperature (77 K). The samples were degassed in vacuum at 623 K for 3 h to remove physically adsorbed components prior to the measurements. The specific surface area was determined from the linear portion of the BET plot. The pore size distribution was calculated from the desorption branch of the N₂ adsorption isotherm using the Barrett-Joyner-Halenda (BJH) formula.

In the TPSR experiments, 100 mg sample (γ-Al₂O₃, TiO₂ or CeO₂) was first treated in pure Ar (99.99%) from room temperature to 673 K at a rate of 10 K/min and held for 1 h at 673 K, then cooled down to room temperature (RT) in the same atmosphere. After pretreatment, 1% H₂S/N₂ (30 ml/min) was passed over the surface of ceria at RT for 20 min to get saturated adsorption. The sample was swept by Ar (50 ml/min) until the gas chromatograph (GC) signal was stable, then the temperature was increased from RT to 673 K at a rate of 10 K/min. For ceria, besides the pretreatment in pure Ar (99.99%), 5% H₂/Ar and 5% O₂/Ar were also used as the pretreatment atmosphere. The flow rate was 30 ml/min. The other steps were the same as in the pretreatment in pure Ar (99.99%) except that a mass spectrometer (MS) was the detector.

In the recycle adsorption experiment, the sample was first

treated with 5% O₂/Ar from RT to 873 K at a rate of 10 K/min and held for 1 h at 873 K, then cooled to RT in the same atmosphere. After pretreatment, 1% H₂S/N₂ (30 ml/min) was passed over the surface of the ceria at RT for 20 min to get saturated adsorption. Before the desorption, the sample was swept by Ar (30 ml/min) until the MS signal was stable, then the temperature was increased from RT to 873 K at a rate of 10 K/min and it was kept at 873 K for 4 h until the MS signal was flat for the first desorption process. This process was named the first cycle. After the first cycle, the ceria sample was cooled down to RT in Ar (99.99%), and H₂S adsorption was carried out at RT for 20 min. The temperature was increased from RT to 873 K at a rate of 10 K/min and it was kept at 873 K for 4 h until the MS signal was flat during the second desorption process. This process was named the second cycle. For the third cycle, the ceria sample was again treated with 5% O₂/Ar from RT to 873 K at a rate of 10 K/min and held for 1 h at 873 K then cooled down to RT in the same atmosphere. The desorption process was the same as in the first and the second cycles. For the fourth cycle, the treatment process and desorption process were the same as for the second cycle. All of the desorption processes used Ar (99.99%) as the carrier gas.

2 Results and discussion

The physical properties of the three samples were characterized using the physical adsorption of N₂. As shown in Table 1, the surface area, pore volume, and average pore diameter of ceria were smaller than those of the other two samples.

Table 1 Physical properties of CeO₂, TiO₂, and γ -Al₂O₃

Sample	Surface area (m ² /g)	Pore volume (cm ³ /g)	Average pore diameter (nm)
CeO ₂	68.3	0.108	6.34
TiO ₂	100.5	0.252	10.0
γ -Al ₂ O ₃	204.6	0.423	8.26

γ -Al₂O₃, TiO₂, and CeO₂ were studied by H₂S-TPSR experiment. The GC signals are shown in Fig. 1. Only one desorption peak was observed at 370 K for γ -Al₂O₃. Two desorption peaks were present for TiO₂. The peak area of the low temperature peak at 340 K was much smaller than that at 580 K. Chen et al. [13] also observed this phenomenon with γ -Al₂O₃ and TiO₂ samples, and they assigned the peak at low temperature to H₂S and the other peak at high temperature to SO₂. TiO₂ has more active surface oxygen than γ -Al₂O₃, which favored the conversion of adsorbed H₂S to SO₂. There was also one desorption peak for ceria but the temperature was increased to 480 K. The desorption peak area on ceria was the highest of the three samples. Since GC

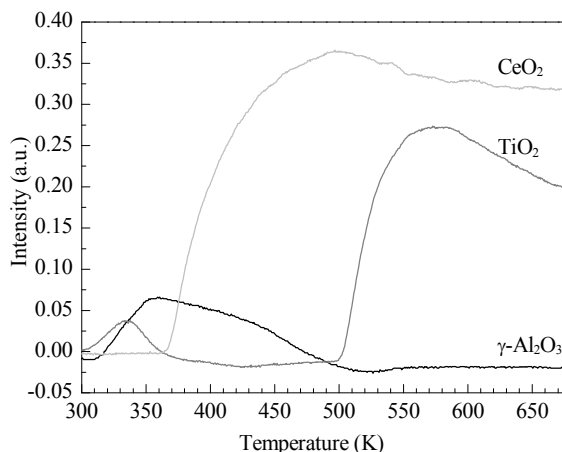


Fig. 1. H₂S-TPSR spectra from γ -Al₂O₃, TiO₂, and CeO₂.

is not a good detector for different sulfur species, the H₂S-TPSR signals were detected by MS in the following experiments.

The adsorption and reaction of H₂S on ceria were further studied by TPSR experiments in which the samples were pretreated in three different gas atmospheres. The H₂S and SO₂ MS signals are shown in Figs. 2 and 3, respectively. The H₂S and SO₂ signals were recorded from 373 to 573 K and had a center at 453 K. The H₂S and SO₂ desorption peak areas after the three different gas atmosphere pretreatments are summarized in Table 2. The desorbed H₂S peak area from ceria after different pretreatment decreased in the order of O₂ > Ar > H₂. The desorbed SO₂ peak area decreased in the order of O₂ > H₂ > Ar. The SO₂ formed after the O₂ pretreatment was mainly from the reaction of H₂S with the surface oxygen of ceria. On the other hand, SO₂ formed after the H₂ pretreatment was from the reaction CeO_n + H₂S → Ce₂O₂S + SO₂ + H₂O, which was similar to the sulfidation process with reduced ceria as the adsorbent [8]. H₂S tended to react with reduced ceria, and did not just directly desorb from the reduced ceria. The H₂S conversion was

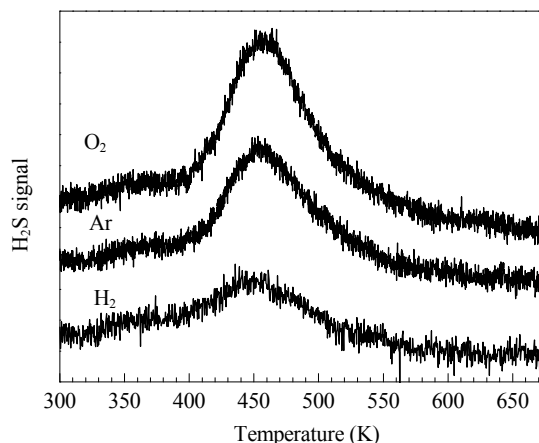


Fig. 2. TPSR H₂S signals from ceria after O₂, Ar, or H₂ pretreatment.

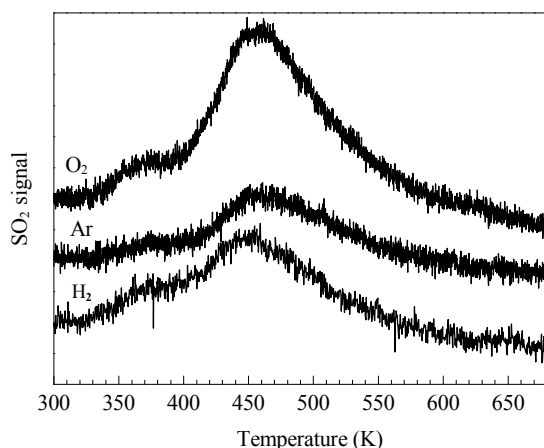


Fig. 3. SO₂ signals during H₂S-TPSR on ceria after O₂, Ar, or H₂ pretreatment.

Table 2 Adsorption and conversion of H₂S on ceria

Pretreatment condition	Peak area*			X(H ₂ S)/%
	H ₂ S	SO ₂	Total	
Ar	1	1	2	46.8
H ₂	0.56	1.58	2.14	71.2
O ₂	1.59	2.66	4.25	59.5

*Defined as 1 from the Ar pretreatment.

calculated as $X(\text{H}_2\text{S}) = [\text{SO}_2]/([\text{H}_2\text{S}] + [\text{SO}_2]) \times 100\%$. The results are also shown in Table 2.

The total peak areas from H₂S and SO₂ desorption were much higher for the sample pretreatment with O₂ than with the other pretreatments with H₂ and Ar. The active oxygen species formed during O₂ pretreatment can oxidize part of adsorbed H₂S to SO₂, and SO₂ was desorbed together with unreacted H₂S between 473 and 673 K. In addition, water and sulfur were observed on the outside of the quartz reactor below 473 K. Water and sulfur may form by two possible ways. One possible way was the reaction of H₂S with oxygen species (O*) at a relative low temperature, by the reaction $\text{H}_2\text{S} + \text{O}^* \leftrightarrow \text{S} + \text{H}_2\text{O}$. This had been reported in the H₂S-TPSR experiments with a reducible TiO₂ support [13]. The other possible way was the Claus reaction ($\text{H}_2\text{S} + \text{SO}_2 = \text{S} + \text{H}_2\text{O}$).

Other than H₂S and SO₂, no other sulfur species were detected in the MS signal until 673 K. However, Ce₂O₂S was formed in the sulfidation process following the H₂ pretreatment and a complex regeneration step was required to recover the adsorbent [14]. From the above discussion, it is preferred to carry out the sulfidation process below 673 K after an O₂ pretreatment to avoid the complex regeneration process.

In order to characterize the reversibility of desulfidation on ceria, recycle experiments were carried out. The H₂S and SO₂ signals in the recycle experiments are shown in Figs. 4

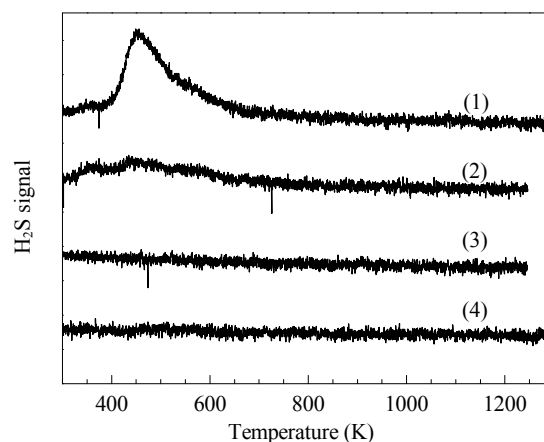


Fig. 4. H₂S signals of the H₂S-TPSR cycle experiments with O₂ pretreatment. (1) First cycle; (2) Second cycle; (3) Third cycle; (4) Fourth cycle.

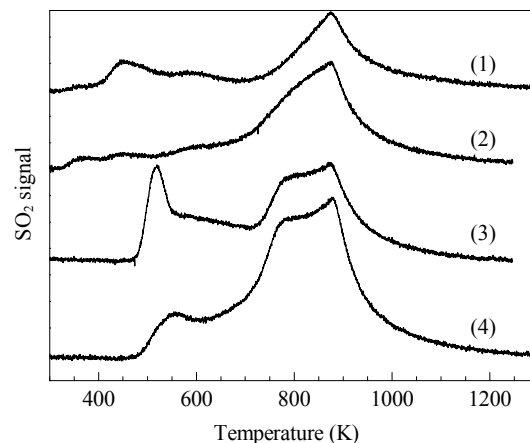


Fig. 5. SO₂ signals of H₂S-TPSR cycle experiments in O₂ pretreatment. (1) First cycle; (2) Second cycle; (3) Third cycle; (4) Fourth cycle.

and 5, respectively, and the four cycles were assigned as 1, 2, 3, and 4. The H₂S and SO₂ peak areas below 673 K in the first cycle were similar as those with the sample pretreated in an O₂ atmosphere at 673 K in the TPSR experiments. During the temperature increase, a sharp SO₂ desorption peak was present near 673 K. The signal increased with the temperature and did not reach a maximum at 873 K. When the desorption temperature was kept at 873 K, it required 40 min to get the desorption signal to decrease to the baseline. The SO₂ desorption peak at high temperature was much larger than that below 673 K, and it was not accompanied by H₂S desorption. The SO₂ desorption peak at 873 K was from the decomposition of Ce(SO₄)₂, which was formed by the reaction of SO₂ with the lattice oxygen of ceria at high temperature. Ce(SO₄)₂ is thermodynamically stable at low temperature and is decomposed to Ce₂O₂S and SO₂ at around 873 K [15].

In the second cycle, the sample after the first cycle was first cooled to 298 K in Ar (99.99%), and then it was used again to adsorb H₂S at 298 K. For the second cycle, most of the surface oxygen had been consumed during the first cycle, therefore, the reaction of H₂S with surface oxygen to form SO₂ was negligible, and this desorbed below 673 K as compared with the first cycle. Thus adsorbed H₂S can only react with the lattice oxygen of ceria to form SO₂, and then SO₂ reacted with lattice oxygen to form sulfate, resulting in more sulfate species as compared with the first cycle. The sulfate species formed was decomposed to release SO₂ at 873 K, which was more than in the first cycle. After the second cycle, the third cycle was carried out, and the process was the same as the first cycle. First, the sample was regenerated in an O₂ atmosphere, and then it was used to adsorb H₂S at 298 K. Finally the adsorption was characterized by TPSR. As shown in Fig. 5, all of the adsorbed H₂S was converted into SO₂ and it desorbed in a wide temperature range between 473 and 873 K. During the regeneration process, active oxygen species were formed on the surface of ceria, such as O²⁻ and O⁻, which readily reacted with H₂S to form SO₂, and the SO₂ produced desorbed at 523 K. There was also a high temperature desorption peak, which was also attributed to the decomposition of sulfate.

After the third cycle, the fourth cycle was carried out, and the details of the process were the same as in the second cycle. It was surprising to note that there was still no desorption peak of H₂S in a full range of the temperature tested, and the SO₂ desorption peak area above 673 K was much larger than the one below 673 K. The reason why there was no H₂S desorption may be due to the presence of excess active oxygen species provided during the previous oxygen regeneration step. From the above H₂S-TPSR experiments, it can be concluded that more sulfate was formed at the high temperature above 673 K. It is preferred to carry out the sulfidation with ceria as adsorbent below 673 K in order to avoid the complex regeneration process.

3 Conclusions

Ceria showed the best desulfidation ability for H₂S among the CeO₂, TiO₂ and γ -Al₂O₃ tested. TPSR experi-

ments demonstrated that H₂S was first adsorbed on the pre-treated ceria at room temperature, then part of the H₂S desorbed below 673 K during the temperature increase in an Ar atmosphere. The other part of H₂S reacted with the surface oxygen of ceria to form different sulfur species at different temperatures. Sulfur and water were formed below 473 K, and SO₂ was formed between 473 and 673 K. SO₂ further reacted with lattice oxygen and was transformed into sulfate above 673 K, which decomposed into SO₂ again around 873 K. Sulfidation with ceria as the adsorbent should be performed below 673 K in order to avoid the complex regeneration process.

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